

8514019 SPRAGUE. SEMICONDS/ICS

93D 03588 D

T-27-90

PLASTIC-CASE BIPOLAR TRANSISTORS

NPN Transistors

'2N' and 'TP' Device Types

ELECTRICAL CHARACTERISTICS at T_A = 25°C

Device Type	I _C Max. (mA)	V _{(BR)CBO} (V)	V _{(BR)CEO} (V)	V _{(BR)EBO} (V)	I _{CBO}		DC Current Gain				V _{CE(sat)}		f _T		C _{ob} ¹ (pF)	t _s ¹ (ns)	NF ¹ (dB)	Process
					Max. (nA)	@V _{CB} (V)	h _{FE} Min.	h _{FE} Max.	@I _C (mA)	@V _{CE} (V)	Max. (V)	@I _C (mA)	Min. (MHz)	@I _C (mA)				
TP5131	100	20	15	3.0	50	10	35	500	10	1.0	1.0	10	100	10	6.0	—	—	FEE
TP5132	100	20	20	3.0	50	10	30	400	10	10	2.0	10	200	10	3.5	—	—	FEE
TP5133	100	20	18	3.0	50	15	60	1000	1.0	5.0	0.4	1.0	40	1.0	5.0	—	—	FEE
2N5135	800	30	25	4.0	300	15	50	600	10	10	1.0	100	40	30	25	—	—	JLA
2N5136	800	30	20	3.0	100	20	20	400	150	1.0	0.25	150	40	50	35	—	—	JLA
TP5137	800	30	20	3.0	100	20	20	400	150	1.0	0.25	150	40	50	35	—	—	JLA
2N5172	500	25	25	5.0	100	25	100	500	10	10	0.25	10	—	—	10	—	—	JGA
2N5174	100	90	75	5.0	500	60	40	600	10	5.0	0.95	10	—	—	5.0	—	—	FEE
TP5189	800	60	35	5.0	500	30	35	—	500	1.0	1.0	1000	250	50	12	70	—	BHB
2N5209	100	50	50	—	50	35	100	300	0.1	5.0	0.7	10	30	0.5	4.0	—	4.0	FEE
2N5210	100	50	50	—	50	35	200	600	0.1	5.0	0.7	10	30	0.5	4.0	—	3.0	FEE
2N5219	100	20	15	3.0	100	10	35	500	2.0	10	0.4	10	150	10	4.0	—	—	FFB
2N5220	500	15	15	3.0	100	10	30	600	50	10	0.5	150	100	20	10	—	—	JGA
2N5223	100	25	20	3.0	100	10	50	800	2.0	10	0.7	10	150	10	4.0	—	—	FFB
2N5225	100	25	25	4.0	300	15	30	600	50	10	0.8	100	50	20	20	—	—	FEE
2N5232	100	70	50	5.0	30	50	250	500	2.0	5.0	0.125	10	—	—	4.0	—	—	FEE
2N5232A	100	70	50	5.0	30	50	250	500	2.0	5.0	0.125	10	—	—	4.0	—	5.0	FEE
2N5249	100	70	50	5.0	30	50	400	800	2.0	5.0	0.125	10	—	—	—	—	—	FEE
2N5249A	100	70	50	5.0	30	50	400	800	2.0	5.0	0.125	10	—	—	—	—	3.0	FEE
2N5305	500	25	25	12	100	25	2k	20k	2.0	5.0	1.4	200	60	2.0	10	—	—	TPM
2N5306	500	25	25	12	100	25	7k	70k	2.0	5.0	1.4	200	60	2.0	10	—	—	TPM
2N5307	500	40	40	12	100	40	2k	20k	2.0	5.0	1.4	200	60	2.0	10	—	—	TPM
2N5308	500	40	40	12	100	40	7k	70k	2.0	5.0	1.4	200	60	2.0	10	—	—	TPM
2N5310	100	70	50	5.0	10	50	100	300	0.01	5.0	0.125	10	—	—	—	—	—	FEE
TP5368	500	60	30	5.0	50	40	60	200	150	10	0.3	150	250	20	8.0	350	—	DCA
TP5369	500	60	30	5.0	50	40	100	300	150	10	0.3	150	250	20	8.0	350	—	DCA
TP5370	500	60	30	5.0	50	40	200	600	150	10	0.3	150	250	20	8.0	400	—	DCA
TP5371	500	40	30	5.0	50	30	60	600	150	10	0.3	150	250	20	8.0	400	—	DCA
TP5376	500	60	30	5.0	10	30	120	—	1.0	5.0	—	—	—	—	8.0	—	—	JGA
TP5377	500	60	30	5.0	10	30	100	—	1.0	5.0	—	—	—	—	8.0	—	—	JGA
TP5380	100	60	40	6.0	50	30	50	150	10	1.0	0.2	10	250	10	4.0	225	6.0	FFB
TP5381	100	60	40	6.0	50	30	100	300	10	1.0	0.2	10	300	10	4.0	250	5.0	FFB
2N5418	500	25	25	4.0	100	25	40	120	50	1.0	0.25	50	—	—	6.0	—	—	JGA
2N5419	500	25	25	4.0	100	25	100	300	50	1.0	0.25	50	—	—	6.0	—	—	JGA
2N5420	500	25	25	4.0	100	25	250	500	50	1.0	0.25	50	—	—	6.0	—	—	JGA
TP5449	500	50	30	5.0	100	20	100	300	50	2.0	0.6	100	100	50	12	—	—	JGA
TP5450	500	50	30	5.0	100	20	50	150	50	2.0	0.8	100	100	50	12	—	—	JGA
TP5451	500	40	20	5.0	100	20	30	600	50	2.0	1.0	100	100	50	12	—	—	JGA
2N5550	600	160	140	6.0	100	100	60	250	10	5.0	0.15	10	100	10	6.0	—	10	VXA
2N5551	600	180	160	6.0	50	120	80	250	10	5.0	0.15	10	100	10	6.0	—	8.0	VXA
2N5770	50	30	15	4.5	10	15	50	200	8.0	10	0.4	10	90	8.0	1.1	—	6.0	DMA
2N5772	500	40	15	5.0	500	20	30	120	30	0.4	0.2	30	350	30	5.0	28	—	BJB

NOTES:

- 1) Maximum at typical JEDEC conditions.
- 2) μA.

3) V_{(BR)CES}/I_{CES}, as applicable.

4) mA.

5) V_{(BR)CER} at R=10Ω.